

### **Operational Amplifiers**

# **Ground Sense Operational Amplifiers**

### LM358xxx LM324xxx LM2904xxx LM2902xxx

#### **General Description**

LM358xxx and LM2904xxx series are dual ground sense operational amplifiers. LM324xxx and LM2902xxx series are quad. These have features of low current consumption and wide operating voltage range from 3V to 32V (single power supply).

#### Features

- Operable with a Single Power Supply
- Wide Operating Supply Voltage Range
- Input/output Ground Sense
- High Large Signal Voltage Gain

#### Applications

- Current Sense Application
- Buffer Application Amplifier
- Active Filter
- Consumer Electronics

#### **Key Specifications**

- Operating Supply Voltage (Single Supply):
- 3.0V to 32.0V

   Operating Temperature Range:

   LM358xxx:

   LM324xxx:

   -40°C to +85°C

   LM2904xxx:

   LM2902xxx:

   Input Offset Voltage:

   Input Bias Current:

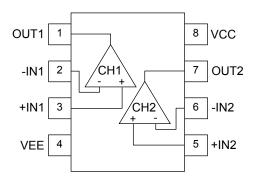
   20nA (Typ)

#### Packages

SOP8 SOP-J8 SSOP-B8 TSSOP-B8 TSSOP-B8J MSOP8 SOP14 SOP-J14 SSOP-B14 TSSOP-B14J W(Typ) x D(Typ) x H(Max) 5.00mm x 6.20mm x 1.71mm 4.90mm x 6.00mm x 1.65mm 3.00mm x 6.40mm x 1.35mm 3.00mm x 6.40mm x 1.20mm 3.00mm x 4.90mm x 1.10mm 2.90mm x 4.00mm x 0.90mm 8.70mm x 6.20mm x 1.71mm 8.65mm x 6.00mm x 1.65mm 5.00mm x 6.40mm x 1.35mm

#### **Pin Configuration**

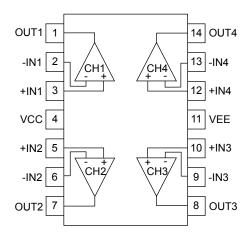
LM358F, LM2904F	: SOP8
LM358FJ, LM2904FJ	: SOP-J8
LM358FV, LM2904FV	: SSOP-B8
LM358FVT, LM2904FVT	: TSSOP-B8
LM358FVJ, LM2904FVJ	: TSSOP-B8J
LM358FVM, LM2904FVM	: MSOP8



Pin No.	Pin Name
1	OUT1
2	-IN1
3	+IN1
4	VEE
5	+IN2
6	-IN2
7	OUT2
8	VCC

OProduct structure : Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays.

: SOP14
: SOP-J14
: SSOP-B14
: TSSOP-B14J



Pin No.	Pin Name
1	OUT1
2	-IN1
3	+IN1
4	VCC
5	+IN2
6	-IN2
7	OUT2
8	OUT3
9	-IN3
10	+IN3
11	VEE
12	+IN4
13	-IN4
14	OUT4

### Absolute Maximum Ratings (T<sub>A</sub>=25°C)

Symbol		Rating						
	Symbol	LM358xxx	LM324xxx	LM2904xxx	LM2902xxx	Unit		
	$V_{CC}$ - $V_{EE}$		3	6		V		
	SOP8	0.68 <sup>(Note 1,9)</sup>	-	0.68 <sup>(Note 1,9)</sup>	-			
	SOP-J8	0.67 <sup>(Note 2,9)</sup>	-	0.67 <sup>(Note 2,9)</sup>	-	1		
	SSOP-B8	0.62 <sup>(Note 3,9)</sup>	-	0.62 <sup>(Note 3,9)</sup>	-			
	TSSOP-B8	0.62 <sup>(Note 3,9)</sup>	-	0.62 <sup>(Note 3,9)</sup>	-	W		
	TSSOP-B8J	0.58 <sup>(Note 4,9)</sup>	-	0.58 <sup>(Note 4,9)</sup>	-			
PD	MSOP8	0.58 <sup>(Note 4,9)</sup>	-	0.58 <sup>(Note 4,9)</sup>	-			
	SOP14	-	0.56 <sup>(Note 5,9)</sup>	-	0.56 <sup>(Note 5,9)</sup>			
	SOP-J14	-	1.02 <sup>(Note 6,9)</sup>	-	1.02 (Note 6,9)			
	SSOP-B14	-	0.87 <sup>(Note 7,9)</sup>	-	0.87 <sup>(Note 7,9)</sup>			
		TSSOP-B14J	-	0.85 <sup>(Note 8,9)</sup>	-	0.85 <sup>(Note 8,9)</sup>		
Voltage (Note 10)		36						
	VICM	(V <sub>EE</sub> -0.3) to (V <sub>EE</sub> +36) ±10						
	h							
V <sub>opr</sub> T <sub>opr</sub>		3.0 to 32.0				V		
		-40 to	o +85	-40 to	°C			
	T <sub>stg</sub>	-55 to +150						
	T <sub>jmax</sub>		15	50		°C		
	P <sub>D</sub>	SOP8           SOP-J8           SSOP-B8           TSSOP-B8           TSSOP-B8J           MSOP8           SOP14           SOP-J14           SOP-B14           TSSOP-B14J           VID           VICM           I           Vopr           Topr           Tsg	Image:	$\begin{tabular}{ c c c c } \hline LM358xxx & LM324xxx \\ \hline Ucc-V_{EE} & & & & & & & & & & & & & & & & & & $	$\begin{tabular}{ c                                   $	$\begin{tabular}{ c                                   $		

(Note 1) Reduce by 5.5mW per 1°C above 25°C. (Note 2) Reduce by 5.4mW per 1°C above 25°C.

(Note 3) Reduce by 5.0mW per 1°C above 25°C.

(Note 4) Reduce by 4.7mW per 1°C above 25°C.

(Note 5) Reduce by 4.5mW per 1°C above 25°C.

(Note 6) Reduce by 9.2mW per 1°C above 25°C.

(Note 7) Reduce by 7.0mW per 1°C above 25°C.

(Note 8) Reduce by 6.8mW per 1°C above 25°C.

(Note 9) Mounted on an FR4 glass epoxy PCB 70mm×70mm×1.6mm (Copper foil area less than 3%).

(Note 10) Differential Input Voltage is the voltage difference between the inverting and non-inverting inputs.

The input pin voltage is set to more than VEE.

(Note 11) An excessive input current will flow when input voltages of less than  $V_{\text{EE}}$ -0.6V are applied.

The input current can be set to less than the rated current by adding a limiting resistor.

Caution: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

#### **Electrical Characteristics**

OLM358xxx, LM2904xxx (Unless otherwise specified V<sub>CC</sub>=+5V, V<sub>EE</sub>=0V)

	nac apcon		VEE-OV	,				
Parameter	Symbol	Temperature		Limits		Unit	Condition	
		Range	Min	Тур	Max			
Input Offset Voltage <sup>(Note 12,13)</sup>	Vio	25°C	-	1	4.5	mV	V <sub>OUT</sub> =1.4V	
input oncet voltage	VIO	Full Range	-	-	5		$V_{CC}$ =5 to 30V, $V_{OUT}$ =1.4V	
Input Offset Voltage Drift <sup>(Note 12)</sup>	ΔV <sub>IO</sub> /ΔT	-	-	6	-	µV/°C	Vout=1.4V	
	-	25°C	-	2	50			
Input Offset Current <sup>(Note 12,13)</sup>	lio	Full Range	-	-	200	nA	V <sub>OUT</sub> =1.4V	
(Note 12.13)		25°C	-	20	250			
Input Bias Current <sup>(Note 12,13)</sup>	lΒ	Full Range	-	-	300	nA	V <sub>OUT</sub> =1.4V	
0 l 0 (Alata 12)		25°C	-	0.6	1.2		D 440 4	
Supply Current <sup>(Note 13)</sup>	lcc	Full Range	-	-	1.5	mA	R∟=∞, All Op-Amps	
	.,	25°C	3.5	-	-	.,	R∟=2kΩ	
Maximum Output Voltage (High) <sup>(Note 13)</sup>	Vон	Full Range	27	28	-	V	V <sub>CC</sub> =30V, R <sub>L</sub> =10kΩ	
Maximum Output Voltage (Low) <sup>(Note 13)</sup>	V <sub>OL</sub>	Full Range	-	5	20	mV	R <sub>L</sub> =∞	
	Av		25	100	-	V/mV	R∟≧2kΩ, V <sub>CC</sub> =15V	
Large Signal Voltage Gain		25°C	88	100	-	dB	V <sub>OUT</sub> =1.4 to 11.4V	
Input Common-mode Voltage Range	VICM	25°C	0	-	3.5	V	V <sub>ICM</sub> =V <sub>EE</sub> to (V <sub>CC</sub> -1.5V) V <sub>OUT</sub> =1.4V	
Input Common-mode Voltage Range (VEE side) (Note 14)	VICM	Full Range	-	0.1	-	V	V <sub>OUT</sub> =1.4V	
Common-mode Rejection Ratio	CMRR	25°C	70	80	_	dB	V <sub>OUT</sub> =1.4V	
Power Supply Rejection Ratio	PSRR	25°C	65	100	-	dB	V <sub>cc</sub> =5 to 30V	
		25°C	20	30	-		V+IN=1V, V-IN=0V V <sub>OUT</sub> =0V, Short Current	
Output Source Current <sup>(Note 13,15)</sup>	ISOURCE	Full Range	10	-	-	mA		
		25°C	20	27	-		V+IN=0V, V-IN=1V	
Output Sink Current <sup>(Note 13,15)</sup>	Isink	Full Range	5	-	-	mA	$V_{+IN}=0V, V_{-IN}=1V$ Vout=5V, Short Current	
		25°C	20	50	-	μA	V <sub>+IN</sub> =0V, V <sub>-IN</sub> =1V V <sub>OUT</sub> =200mV	
Channel Separation	CS	25°C	_	120	_	dB	f=1kHz, Input Referred	
Slew Rate	SR	25°C	-	0.3	-	V/µs	V <sub>CC</sub> =15V, Av=0dB R <sub>L</sub> =2kΩ, C <sub>L</sub> =100pF	
Gain Bandwidth	GBW	25°C	-	0.8	-	MHz	$V_{CC}=15V, V_{EE}=-15V$ RL=2k $\Omega, C_{L}=100pF$	
Phase Margin	θ	25°C	-	80	_	deg	Av=40dB	
Input Referred Noise Voltage	VN	25°C	_	40	_	nV/√Hz	V <sub>CC</sub> =15V, V <sub>EE</sub> =-15V R <sub>S</sub> =100Ω, V <sub>IN</sub> =0V, f=1kH	

(Note 12) Absolute value

(Note 13) LM358xxx Full Range: T<sub>A</sub>=-40°C to +85°C, LM2904xxx Full Range: T<sub>A</sub>=-40°C to +125°C

(Note 14) LM2904xxx only.

(Note 15) Consider the power dissipation of the IC under high temperature when selecting the output current value.

There may be a case where the output current value is reduced due to the rise in IC temperature caused by the heat generated inside the IC.

#### **Electrical Characteristics - continued**

OLM324xxx, LM2902xxx (Unless otherwise specified V<sub>CC</sub>=+5V, V<sub>EE</sub>=0V)

Parameter	Symbol	Temperature		Limits		Unit	Condition	
	e y iniser	Range	Min	Тур	Max	orme		
Input Offset Voltage <sup>(Note 16,17)</sup>	Vio	25°C	-	1	4.5	mV	Vout=1.4V	
input Onset Voltage	VIO	Full Range	-	-	5	IIIV	$V_{CC}$ =5 to 30V, $V_{OUT}$ =1.4V	
Input Offset Voltage Drift <sup>(Note 17)</sup>	ΔV <sub>IO</sub> /ΔT	-	-	6	-	µV/°C	Vout=1.4V	
Input Offset Current <sup>(Note 16,17)</sup>	lia	25°C	-	2	50	nA	Vout=1.4V	
input Onset Currentente only	lio	Full Range	-	-	200	IIA	V001-1.4V	
Input Bias Current <sup>(Note 16,17)</sup>	I_	25°C	-	20	250	54	Vout=1.4V	
Input Blas Current (1989 1997)	lв	Full Range	-	-	300	nA	VOUT=1.4V	
Supply Current <sup>(Note 17)</sup>	1	25°C	-	1	2	<b>m</b> 4		
Supply Current <sup>(1000 H)</sup>	lcc	Full Range	-	-	2.5	mA	R∟=∞, All Op-Amps	
Maximum Qutput Valtaga (Lligh)(Note 17)	V	25°C	3.5	-	-	v	R∟=2kΩ	
Maximum Output Voltage (High) <sup>(Note 17)</sup>	Vон	Full Range	27	28	-	V	$V_{CC}$ =30V, RL=10k $\Omega$	
Maximum Output Voltage (Low)(Note 17)	V <sub>OL</sub>	Full Range	-	5	20	mV	R <sub>L</sub> =∞	
	Av	25°C	25	100	-	V/mV	R∟≧2kΩ, V <sub>CC</sub> =15V	
Large Signal Voltage Gain		25°C	88	100	-	dB	Vout=1.4 to 11.4V	
Input Common-mode Voltage Range	VICM	25°C	0	-	3.5	V	V <sub>ICM</sub> =V <sub>EE</sub> to (V <sub>CC</sub> -1.5V) V <sub>OUT</sub> =1.4V	
Input Common-mode Voltage Range (VEE side) (Note 18)	VICM	Full Range	-	0.1	-	V	V <sub>OUT</sub> =1.4V	
Common-mode Rejection Ratio	CMRR	25°C	70	80	-	dB	V <sub>OUT</sub> =1.4V	
Power Supply Rejection Ratio	PSRR	25°C	65	100	-	dB	V <sub>CC</sub> =5 to 30V	
		25°C	20	30	-		$V_{+IN}$ =1V, $V_{-IN}$ =0V $V_{OUT}$ =0V, Short Current	
Output Source Current <sup>(Note 17,19)</sup>	ISOURCE	Full Range	10	-	-	mA		
		25°C	20	27	-		V+IN=0V, V-IN=1V	
Output Sink Current <sup>(Note 17,19)</sup>	Isink	Full Range	5	-	-	mA	Vout=5V, Short Current	
		25°C	20	50	-	μA	V <sub>+IN</sub> =0V, V <sub>-IN</sub> =1V V <sub>OUT</sub> =200mV	
Channel Separation	CS	25°C	-	120	-	dB	f=1kHz, Input Referred	
Slew Rate	SR	25°C	-	0.3	-	V/µs	V <sub>CC</sub> =15V, Av=0dB R <sub>L</sub> =2kΩ, C <sub>L</sub> =100pF	
Gain Bandwidth	GBW	25°C	-	0.8	-	MHz	$V_{CC}=15V, V_{EE}=-15V$ R <sub>L</sub> =2k $\Omega, C_{L}=100pF$	
Phase Margin	θ	25°C	-	80	-	deg	Av=40dB	
Input Referred Noise Voltage	VN	25°C	-	40	-	nV/√Hz	V <sub>CC</sub> =15V, V <sub>EE</sub> =-15V R <sub>S</sub> =100Ω, V <sub>IN</sub> =0V, f=1kH	

(Note 16) Absolute value

(Note 17) LM324xxx Full Range: T<sub>A</sub>=-40°C to +85°C, LM2902xxx Full Range: T<sub>A</sub>=-40°C to +125°C

(Note 18) LM2902xxx only.

(Note 19) Consider the power dissipation of the IC under high temperature when selecting the output current value.

There may be a case where the output current value is reduced due to the rise in IC temperature caused by the heat generated inside the IC.

#### **Description of Electrical Characteristics**

Below are the descriptions of the relevant electrical terms used in this datasheet. Items and symbols used are also shown. Note that item names, symbols, and their meanings may differ from those of another manufacturer's document or general document.

#### 1. Absolute Maximum Ratings

Absolute maximum rating items indicate the conditions which must not be exceeded. Application of voltage in excess of the absolute maximum rating or use out of absolute maximum rated temperature environment may cause deterioration of electrical characteristics.

(1) Supply Voltage (V<sub>CC</sub>/V<sub>EE</sub>)

Indicates the maximum voltage that can be applied between the VCC pin and VEE pin without deterioration of characteristics of internal circuit.

- (2) Differential Input Voltage (V<sub>ID</sub>) Indicates the maximum voltage that can be applied between the non-inverting and inverting pins without damaging the IC.
- (3) Input Common-mode Voltage Range (V<sub>ICM</sub>) Indicates the maximum voltage that can be applied to the non-inverting and inverting pins without deterioration or destruction of electrical characteristics. Input common-mode voltage range of the maximum ratings does not assure normal operation of IC. For normal operation, use the IC within the input common-mode voltage range characteristics.
- (4) Power Dissipation (P<sub>D</sub>) Indicates the power that can be consumed by the IC when mounted on a specific board at the ambient temperature 25°C (normal temperature). As for package product, P<sub>D</sub> is determined by the temperature that can be permitted by the IC in the package (maximum junction temperature) and the thermal resistance of the package.

#### 2. Electrical Characteristics

- (1) Input Offset Voltage (V<sub>IO</sub>) Indicates the voltage difference between non-inverting pin and inverting pin. It can be translated to the input voltage difference required for setting the output voltage to 0V.
- (2) Input Offset Voltage Drift ( $\Delta V_{IO}/\Delta T$ ) Denotes the ratio of the input offset voltage fluctuation to the ambient temperature fluctuation.
- (3) Input Offset Current (I<sub>IO</sub>) Indicates the difference of input bias current between the non-inverting and inverting pins.
- (4) Input Bias Current (I<sub>B</sub>) Indicates the current that flows into or out of the input pin. It is defined by the average of input bias currents at the non-inverting and inverting pins.
- (5) Supply Current (Icc) Indicates the current that flows within the IC under specified no-load conditions.
- (6) Maximum Output Voltage (High) / Maximum Output Voltage (Low) (V<sub>OH</sub>/V<sub>OL</sub>) Indicates the voltage range of the output under specified load condition. It is typically divided into maximum output voltage high and low. Maximum output voltage high indicates the upper limit of output voltage. Maximum output voltage low indicates the lower limit.
- (7) Large Signal Voltage Gain (Av)
   Indicates the amplification rate (gain) of output voltage against the voltage difference between non-inverting pin and inverting pin. It is normally the amplification rate (gain) with reference to DC voltage.
   Av = (Output Voltage) / (Differential Input Voltage)
- (8) Input Common-mode Voltage Range (V<sub>ICM</sub>)
   Indicates the input voltage range at which IC normally operates.
- (9) Common-mode Rejection Ratio (CMRR) Indicates the ratio of fluctuation of input offset voltage when the input common-mode voltage is changed. It is normally the fluctuation of DC.
   CMRR = (Change of Input Common-mode Voltage)/(Input Offset Fluctuation)

- (10) Power Supply Rejection Ratio (PSRR) Indicates the ratio of fluctuation of input offset voltage when supply voltage is changed. It is normally the fluctuation of DC. PSRR= (Change of Power Supply Voltage)/(Input Offset Fluctuation)
- (11) Output Source Current/ Output Sink Current (I<sub>SOURCE</sub> / I<sub>SINK</sub>) The maximum current that the IC can output under specific output conditions. The output source current indicates the current flowing out from the IC, and the output sink current indicates the current flowing into the IC.
- (12) Channel Separation (CS) Indicates the fluctuation in the output voltage of the driven channel with reference to the change of output voltage of the channel which is not driven.
- (13) Slew Rate (SR)Indicates the rate of the change of the output voltage with time when a step input signal is applied.
- (14) Gain Bandwidth (GBW) The product of the open-loop voltage gain and the frequency at which the voltage gain decreases 6dB/octave.
- (15) Phase Margin (θ)Indicates the margin of phase from 180 degree phase lag at unity gain frequency.
- (16) Input Referred Noise Voltage (V<sub>N</sub>) Indicates a noise voltage generated inside the operational amplifier equivalent by ideal voltage source connected in series with input pin.

#### **Typical Performance Curves** OLM358xxx, LM2904xxx

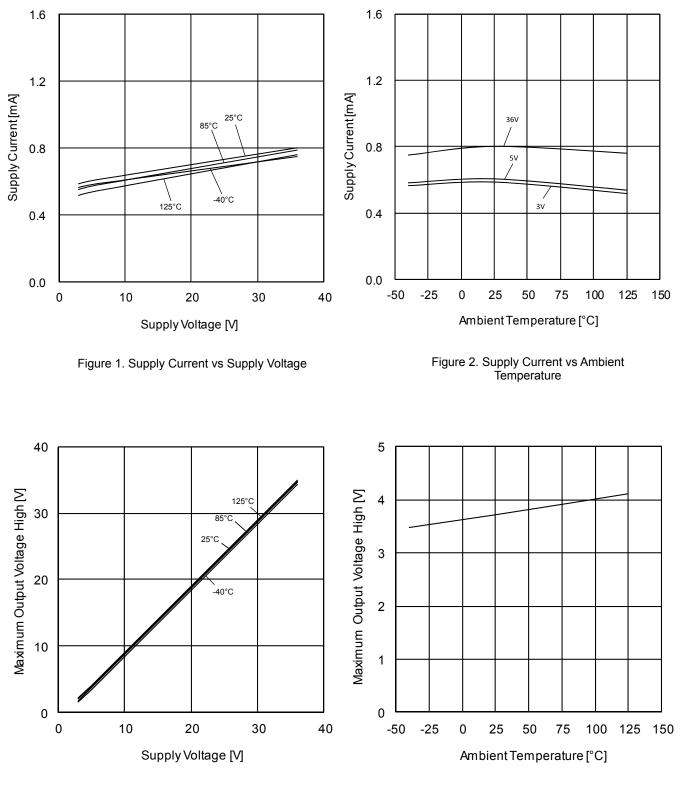
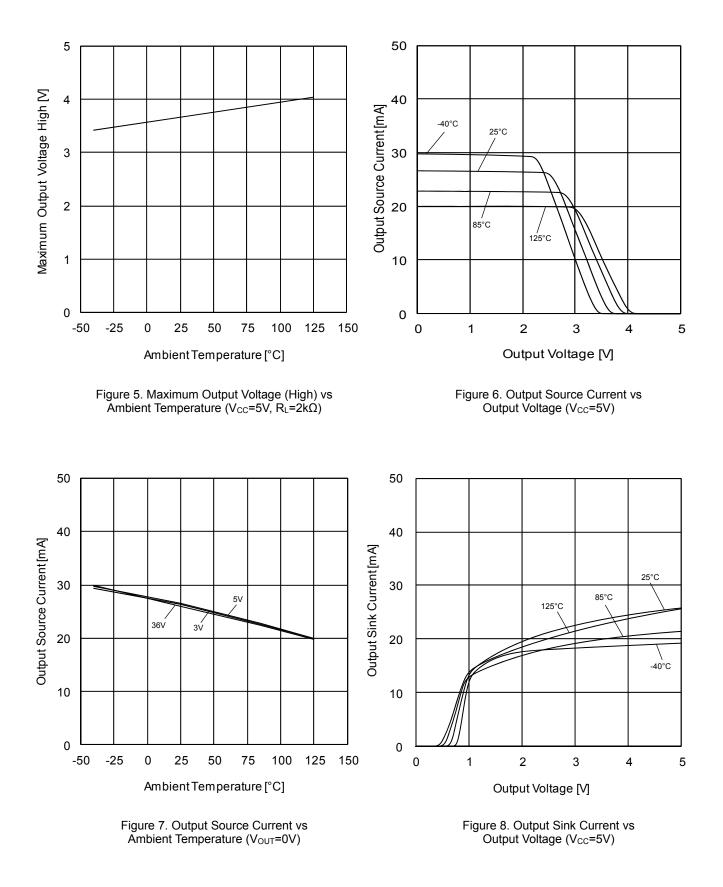


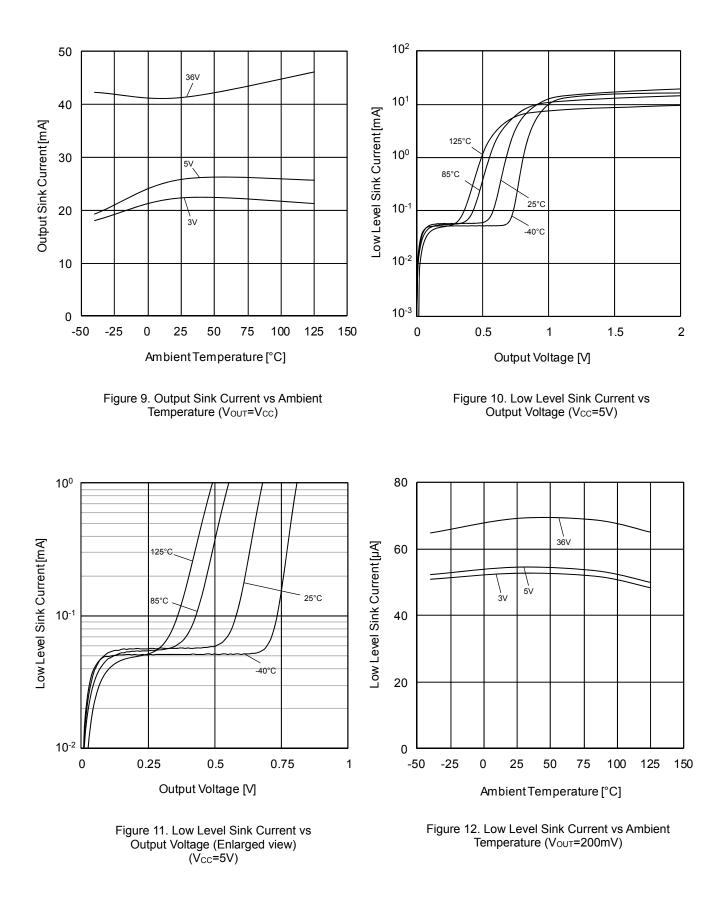
Figure 3. Maximum Output Voltage (High) vs Supply Voltage ( $R_L=10k\Omega$ )

Figure 4. Maximum Output Voltage (High) vs Ambient Temperature ( $V_{CC}=5V$ ,  $R_L=10k\Omega$ )

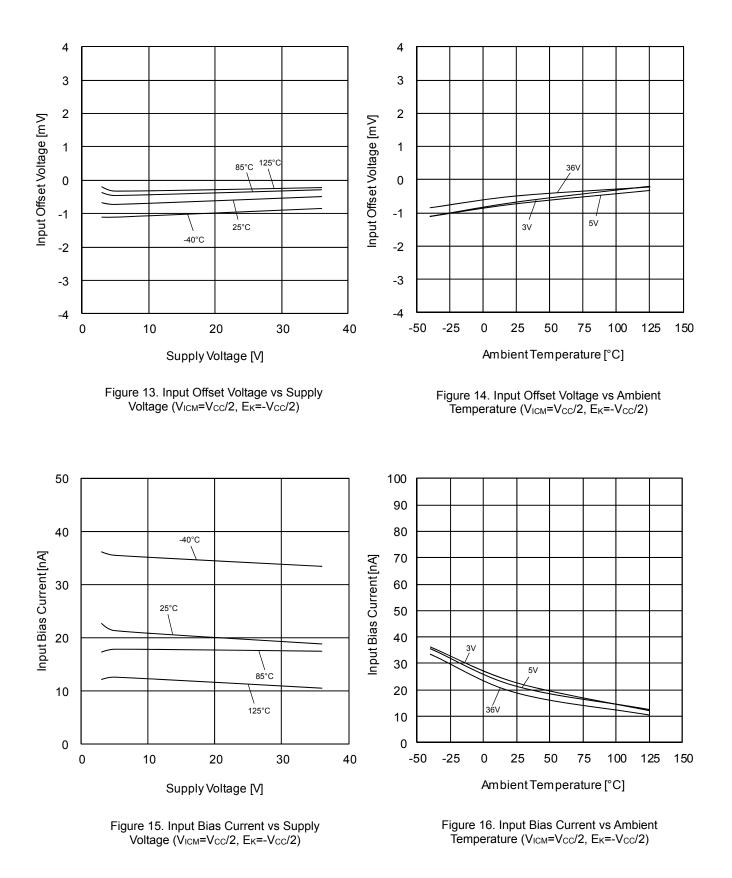
#### Typical Performance Curves - continued OLM358xxx, LM2904xxx



#### Typical Performance Curves - continued OLM358xxx, LM2904xxx



OLM358xxx, LM2904xxx



OLM358xxx, LM2904xxx

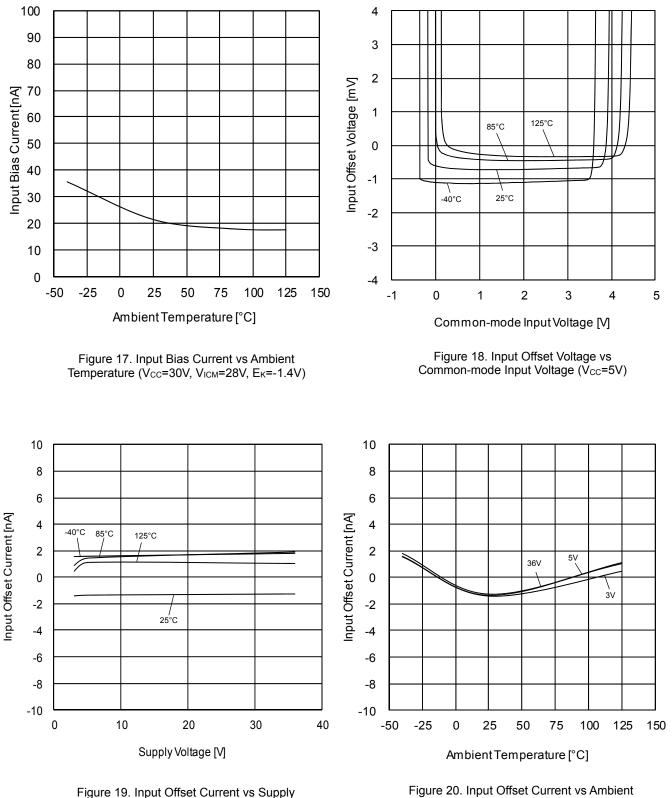
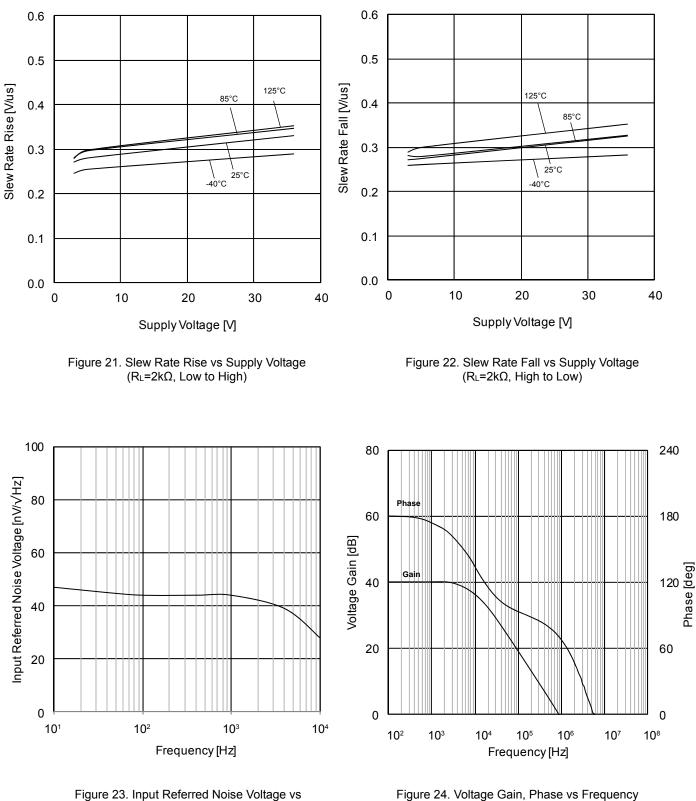


Figure 20. Input Offset Current vs Ambient Temperature (VICM=VCC/2, EK=-VCC/2)

(\*) The above data are measurement value of typical sample, they are not guaranteed. LM358xxx: -40°C to +85°C LM2904xxx: -40°C to 125°C

Voltage (V<sub>ICM</sub>=V<sub>CC</sub>/2, E<sub>K</sub>=-V<sub>CC</sub>/2)

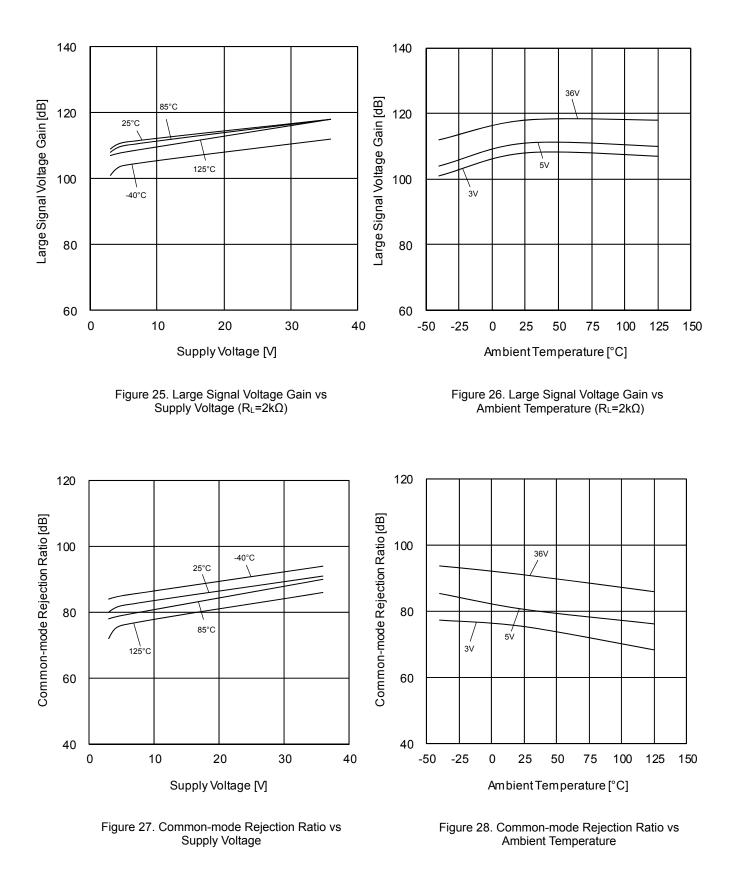
OLM358xxx, LM2904xxx





 $(V_{CC}=30V, R_L=2k\Omega, C_L=100pF)$ 

OLM358xxx, LM2904xxx



#### Typical Performance Curves - continued OLM358xxx, LM2904xxx

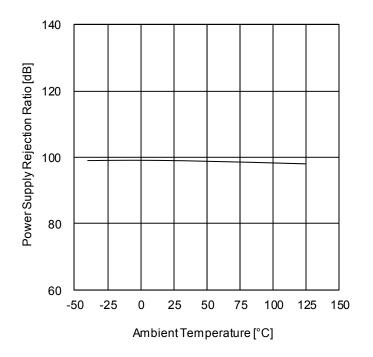
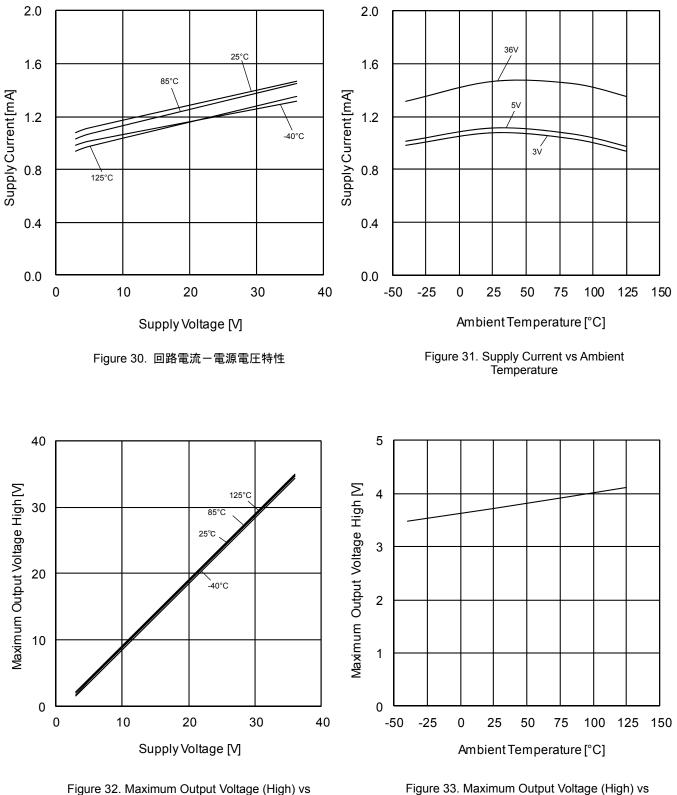
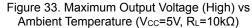


Figure 29. Power Supply Rejection Ratio vs Ambient Temperature

OLM324xxx, LM2902xxx

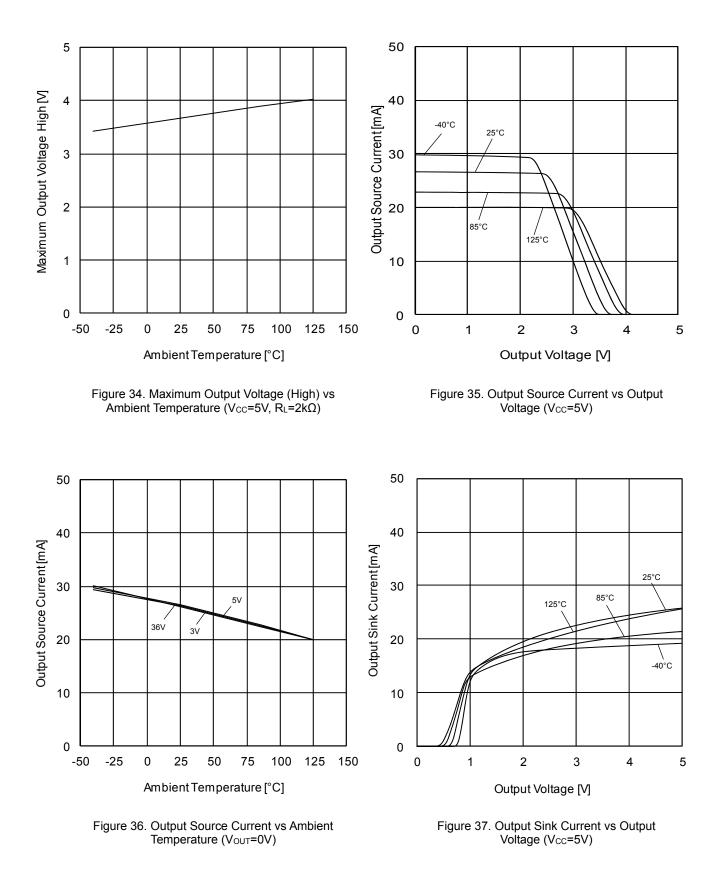




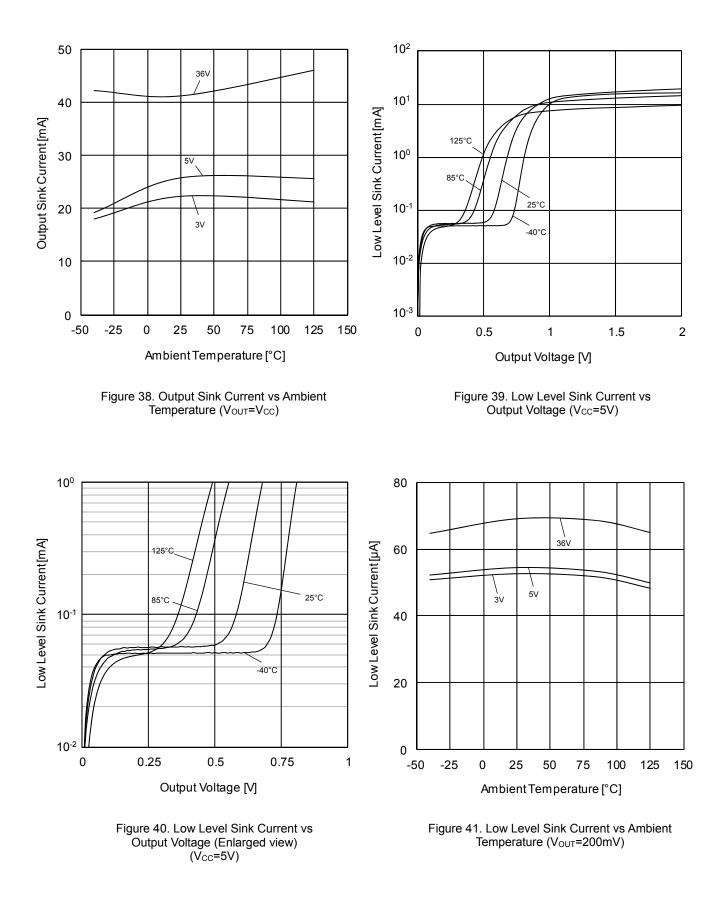
(\*) The above data are measurement value of typical sample, they are not guaranteed. LM2902xxx: -40°C to 125°C LM324xxx: -40°C to +85°C

Supply Voltage (R<sub>L</sub>=10kΩ)

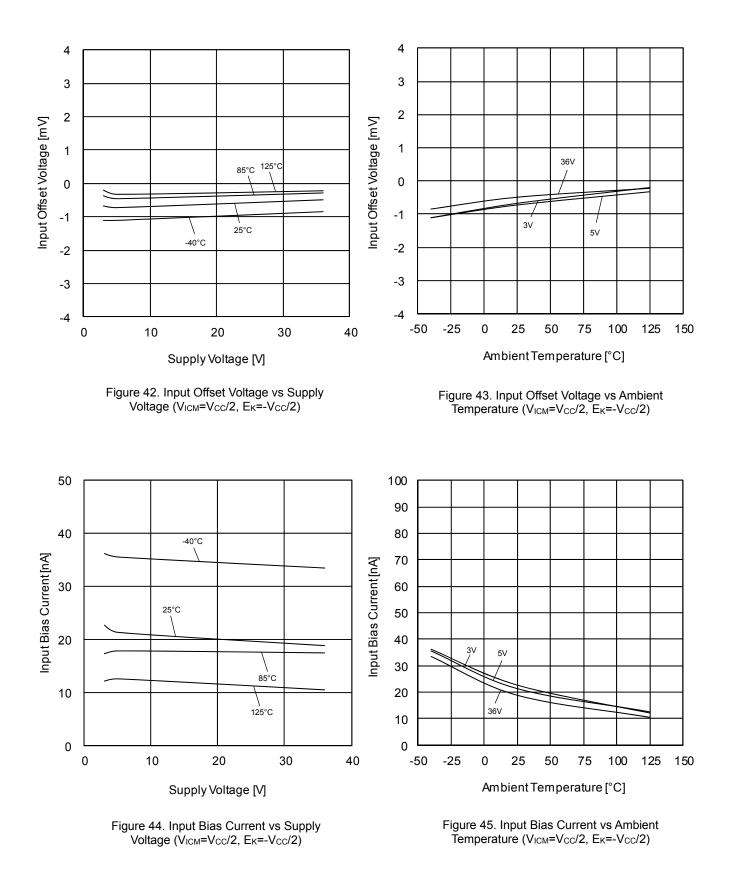
#### Typical Performance Curves - continued OLM324xxx, LM2902xxx



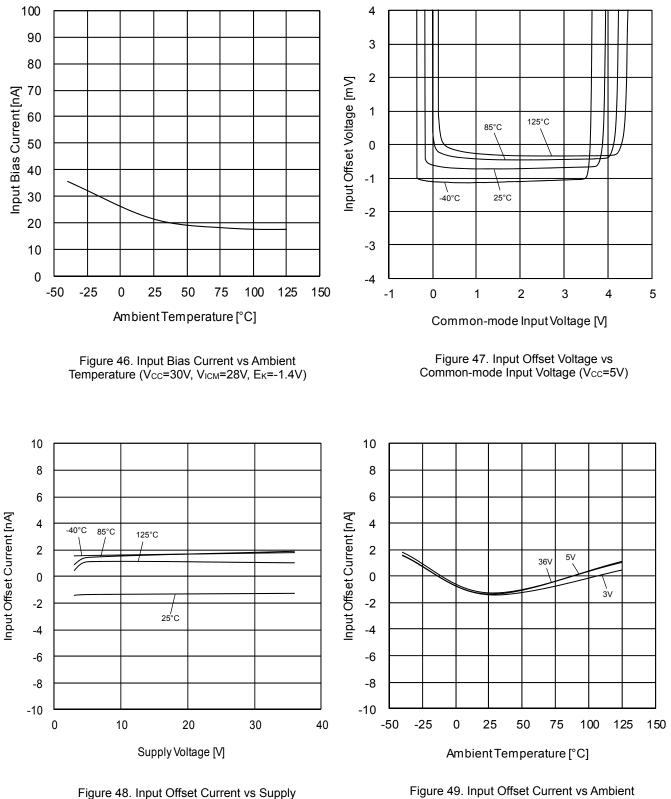
#### Typical Performance Curves - continued OLM324xxx, LM2902xxx



OLM324xxx, LM2902xxx



OLM324xxx, LM2902xxx

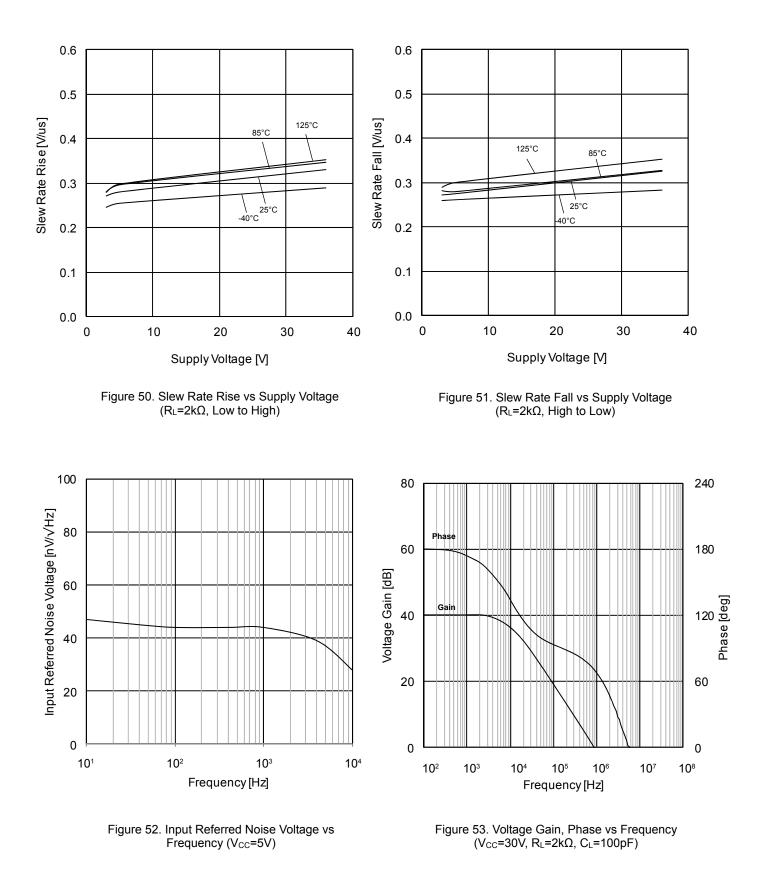


Temperature (VICM=VCc/2, EK=-VCc/2)

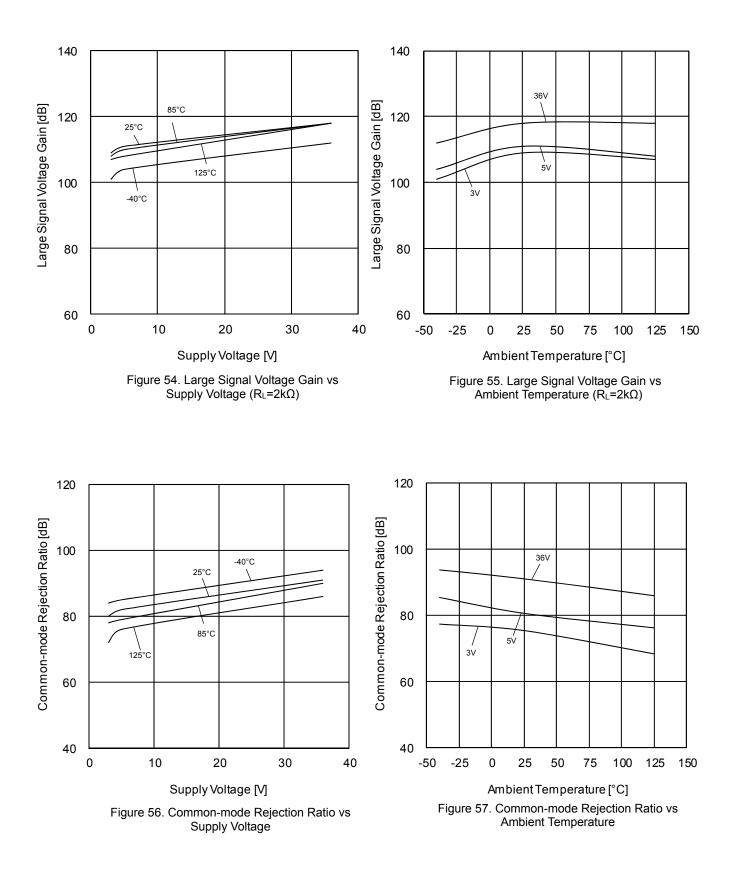
(\*) The above data are measurement value of typical sample, they are not guaranteed. LM324xxx: -40°C to +85°C LM2902xxx: -40°C to 125°C

Voltage (VICM=VCC/2, EK=-VCC/2)

OLM324xxx, LM2902xxx



#### Typical Performance Curves - continued OLM324xxx, LM2902xxx



#### Typical Performance Curves - continued OLM324xxx, LM2902xxx

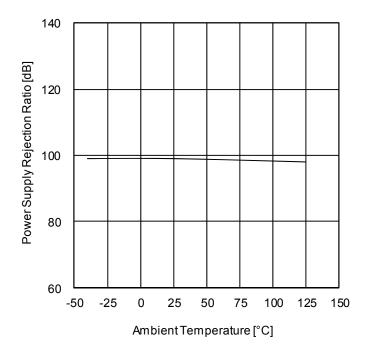


Figure 58. Power Supply Rejection Ratio vs Ambient Temperature

#### Application Information

NULL method condition for Test Circuit 1

							Vcc,	Vee, Ek	, V <sub>ICM</sub> Unit: V
Parameter	VF	SW1	SW2	SW3	Vcc	$V_{EE}$	Ек	VICM	Calculation
Input Offset Voltage	V <sub>F1</sub>	ON	ON	OFF	5 to 30	0	-1.4	0	1
Input Offset Current	V <sub>F2</sub>	OFF	OFF	OFF	5	0	-1.4	0	2
lanut Diag Oursent	V <sub>F3</sub>	OFF	ON	055	-	0	-1.4	0	2
Input Bias Current	V <sub>F4</sub>	ON	OFF	OFF	5	0			3
	V <sub>F5</sub>			ON	15	0	-1.4	0	
Large Signal Voltage Gain	V <sub>F6</sub>	ON	ON				-11.4		4
Common-mode Rejection Ratio	V <sub>F7</sub>			055	-	0		0	_
(Input Common-mode Voltage Range)	VF8 ON	ON	OFF	5	0	-1.4	3.5	5	
Device Overally Delicetion Detic	V <sub>F9</sub>			055	5	0		_	0
Power Supply Rejection Ratio	V <sub>F10</sub>	ON	ON	OFF	30	0	-1.4	0	6

- Calculation -

1. Input Offset Voltage (V<sub>IO</sub>)

$$V_{IO} = \frac{|V_{F1}|}{1 + R_F/R_S}$$
 [V]

2. Input Offset Current (I<sub>IO</sub>)

3. Input Bias Current (IB)

- 4. Large Signal Voltage Gain (A<sub>V</sub>)
- 5. Common-mode Rejection Ratio (CMRR)
- 6. Power Supply Rejection Ratio (PSRR)

$$I_{IO} = \frac{|V_{F2} - V_{F1}|}{R_{I} x (1 + R_{F}/R_{S})}$$
 [A]

$$I_{B} = \frac{|V_{F4} - V_{F3}|}{2 \times R_{I} \times (1 + R_{F}/R_{S})}$$
 [A]

$$Av = 20Log \frac{\Delta E_{K} \times (1+R_{F}/R_{S})}{|V_{F6} - V_{F5}|} \quad [dB]$$

$$CMRR = 20Log \frac{\Delta V_{ICM} \times (1 + R_F/R_S)}{|V_{F8} - V_{F7}|} \quad [dB]$$

$$PSRR = 20Log \frac{\Delta VCC \times (1 + R_F/R_S)}{|V_{F10} - V_{F9}|} \quad [dB]$$

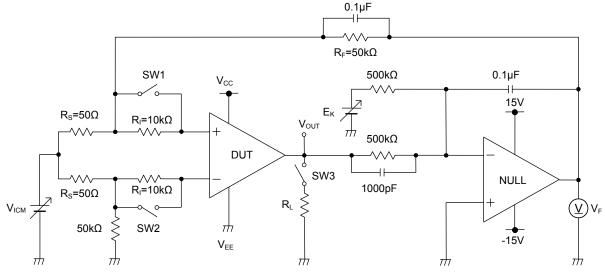


Figure 59. Test Circuit 1 (One Channel Only)

#### Application Information – continued Switch Condition for Test Circuit 2

Parameter	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8	SW9	SW10	SW11	SW12	SW13
Supply Current	OFF	OFF	OFF	ON	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	OFF
Maximum Output Voltage(High)	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	ON	OFF
Maximum Output Voltage(Low)	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	ON	OFF
Output Source Current	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	ON
Output Sink Current	OFF	OFF	ON	OFF	OFF	ON	OFF	OFF	OFF	OFF	OFF	OFF	ON
Slew Rate	OFF	OFF	OFF	ON	OFF	OFF	OFF	ON	ON	ON	OFF	OFF	OFF
Gain Bandwidth Product	OFF	ON	OFF	OFF	ON	ON	OFF	OFF	ON	ON	OFF	OFF	OFF
Input Referred Noise Voltage	ON	OFF	OFF	OFF	ON	ON	OFF	OFF	OFF	OFF	ON	OFF	OFF

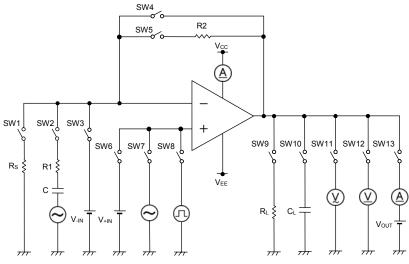


Figure 60. Test Circuit 2 (Each Op-Amp)

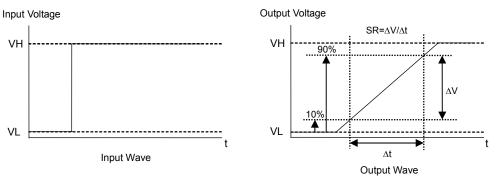


Figure 61. Slew Rate Input and Output Wave

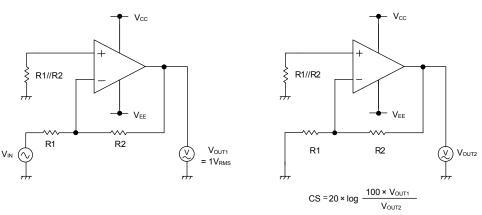


Figure 62. Test Circuit 3 (Channel Separation) (R1=1kΩ,R2=100kΩ)

### **Application Information – continued**

#### 1. **Unused Circuits**

It is recommended to apply the connection (see Figure 63) and set the non-inverting input pin at a potential within the Input Common-mode Voltage Range (V<sub>ICM</sub>) for any unused circuit.

#### 2. **Input Voltage**

Regardless of the supply voltage, applying VEE+36V to the input pin is possible without causing deterioration of the electrical characteristics or destruction. However, this does not ensure normal circuit operation. Please note that the circuit operates normally only when the input voltage is within the common mode input voltage range of the electric characteristics.

#### 3. Power Supply (Single/Dual)

The operational amplifiers operate when the voltage supplied is between VCC pin and VEE pin. Therefore, the single supply operational amplifiers can be used as dual supply operational amplifiers as well.

in VICM

#### 4 **IC Handling**

When pressure is applied to the IC through warp on the printed circuit board, the characteristics may fluctuate due to the piezo effect. Be careful with the warp on the printed circuit board.

#### 5. The IC Destruction Caused by Capacitive Load

The IC may be damaged when VCC pin and VEE pin is shorted with the charged output pin capacitor. When IC is used as an operational amplifier or as an application circuit where oscillation is not activated by an output capacitor, output capacitor must be kept below 0.1µF in order to prevent the damage mentioned above.

#### I/O Equivalent Circuit

Symbol	Pin No.	Equivalent Circuit
+IN -IN	LM358xxx, LM2904xxx: 2,3,5,6 LM324xxx, LM2902xxx: 2,3,5,6,9,10,12,13	
OUT	LM358xxx, LM2904xxx: 1,7 LM324xxx, LM2902xxx: 1,7,8,14	VCC
VCC	LM358xxx, LM2904xxx: 8 LM324xxx, LM2902xxx: 4	VCC

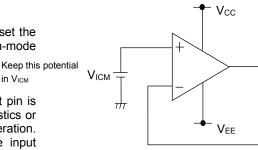


Figure 63. The Example of Application Circuit for Unused Op-amp

#### **Examples of Circuit**

OVoltage Follower

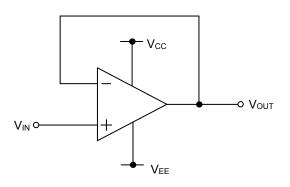


Figure 64. Voltage Follower Circuit

**OInverting Amplifier** 

Voltage gain is 0dB.

Using this circuit, the output voltage (V<sub>OUT</sub>) is configured to be equal to the input voltage (V<sub>IN</sub>). This circuit also stabilizes the output voltage (V<sub>OUT</sub>) due to high input impedance and low output impedance. Computation for output voltage (V<sub>OUT</sub>) is shown below.

Vout=VIN

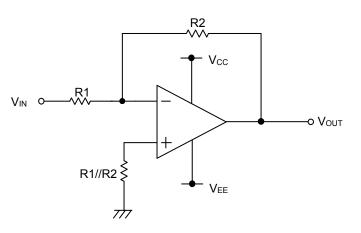


Figure 65. Inverting Amplifier Circuit

For inverting amplifier, input voltage  $(V_{\text{IN}})$  is amplified by a voltage gain and depends on the ratio of R1 and R2. The out-of-phase output voltage is shown in the next expression

V<sub>OUT</sub>=-(R2/R1) · V<sub>IN</sub>

This circuit has input impedance equal to R1.

ONon-inverting Amplifier

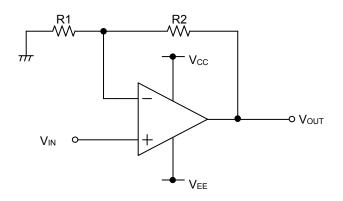


Figure 66. Non-inverting Amplifier Circuit

For non-inverting amplifier, input voltage  $(V_{IN})$  is amplified by a voltage gain, which depends on the ratio of R1 and R2. The output voltage  $(V_{OUT})$  is in-phase with the input voltage  $(V_{IN})$  and is shown in the next expression.

V<sub>OUT</sub>=(1 + R2/R1) · V<sub>IN</sub>

Effectively, this circuit has high input impedance since its input side is the same as that of the operational amplifier.

### **Power Dissipation**

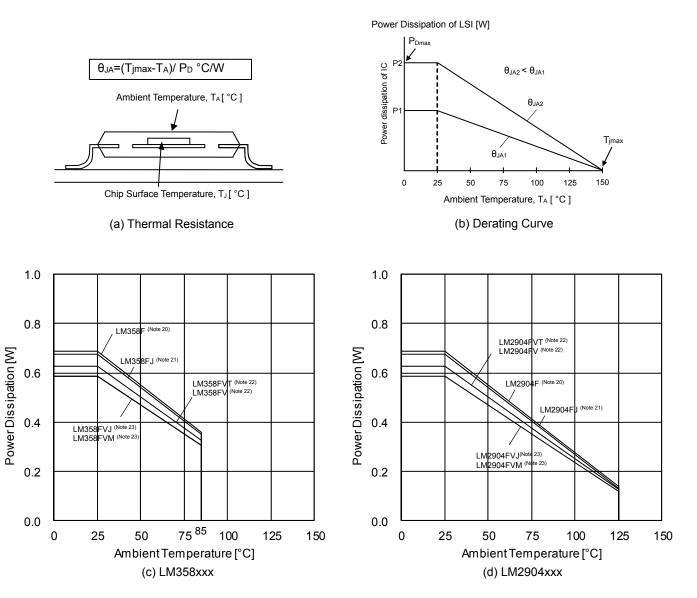
Power dissipation (total loss) indicates the power that the IC can consume at  $T_A=25$ °C (normal temperature). As the IC consumes power, it heats up, causing its temperature to rise above the ambient temperature. The allowable temperature that the IC can accept is limited. This depends on the circuit configuration, manufacturing process, and consumable power.

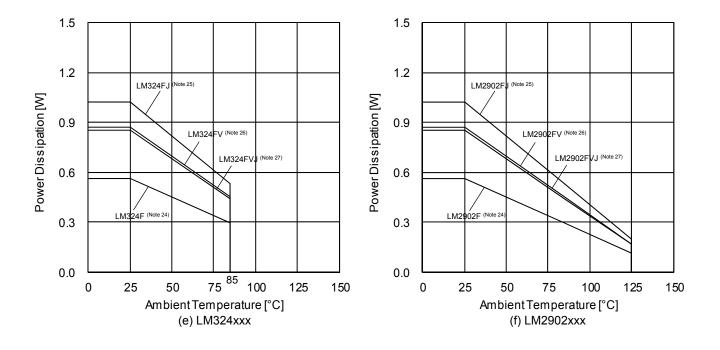
Power dissipation is determined by the allowable temperature within the IC (maximum junction temperature) and the thermal resistance of the package used (heat dissipation capability). Maximum junction temperature is typically equal to the maximum storage temperature. The heat generated through the consumption of power by the IC radiates from the mold resin or lead frame of the package. Thermal resistance, represented by the symbol  $\theta_{JA}^{\circ}C/W$ , indicates this heat dissipation capability. Similarly, the temperature of an IC inside its package can be estimated by thermal resistance.

Figure 67(a) shows the model of the thermal resistance of a package. The equation below shows how to compute for the Thermal resistance ( $\theta_{JA}$ ), given the ambient temperature ( $T_A$ ), maximum junction temperature ( $T_{jmax}$ ), and power dissipation ( $P_D$ ).

$$\theta_{JA} = (T_{jmax} - T_A) / P_D ^{\circ} C/W$$

The Derating Curve in Figure 67(b) indicates the power that the IC can consume with reference to ambient temperature. Power consumption of the IC begins to attenuate at certain temperatures. This gradient is determined by Thermal resistance ( $\theta_{JA}$ ), which depends on the chip size, power consumption, package, ambient temperature, package condition, wind velocity, etc. This may also vary even when the same of package is used. Thermal reduction curve indicates a reference value measured at a specified condition. Figures 67(c) to (f) show the examples of derating curves for LM358xxx, LM2904xxx, LM324xxx, and LM2902xxx respectively.





Note 20	Note 21	Note 22	Note 23	Note 24	Note 25	Note 26	Note 27	Unit
5.5	5.4	5.0	4.7	4.5	8.2	7.0	6.8	mW/°C

When using the unit above  $T_A=25^{\circ}C$ , subtract the value above per Celsius degree.

Power dissipation is the value when FR4 glass epoxy board 70mm × 70mm × 1.6mm (copper foil area below 3%) is mounted.

Figure 67. Thermal Resistance and Derating Curve

#### **Operational Notes**

#### 1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### 2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### 3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

#### 4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### 5. Thermal Consideration

Should by any chance the power dissipation rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. The absolute maximum rating of the  $P_D$  stated in this specification is when the IC is mounted on a 70mm x 1.6mm glass epoxy board. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the  $P_D$  rating.

#### 6. Recommended Operating Conditions

These conditions represent a range within which the expected characteristics of the IC can be approximately obtained. The electrical characteristics are guaranteed under the conditions of each parameter.

#### 7. In-rush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### 8. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

#### 9. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### 10. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### **Operational Notes – continued**

#### 11. Regarding the Input Pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

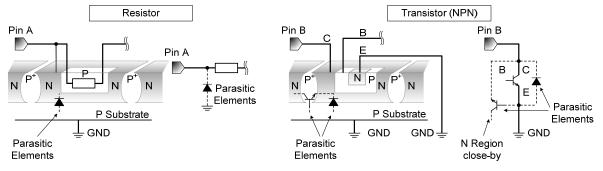
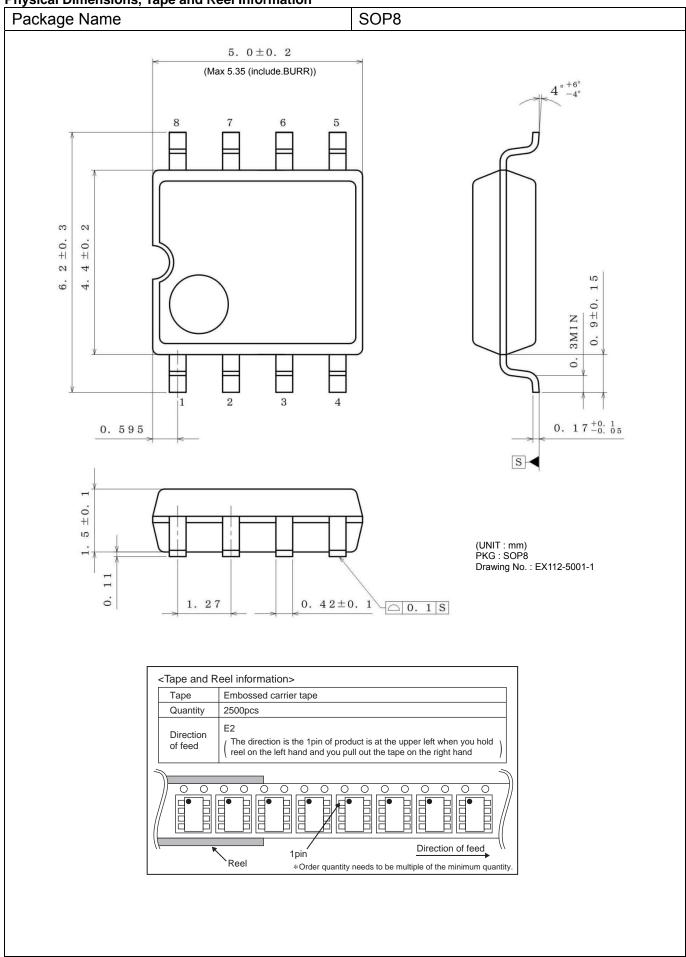
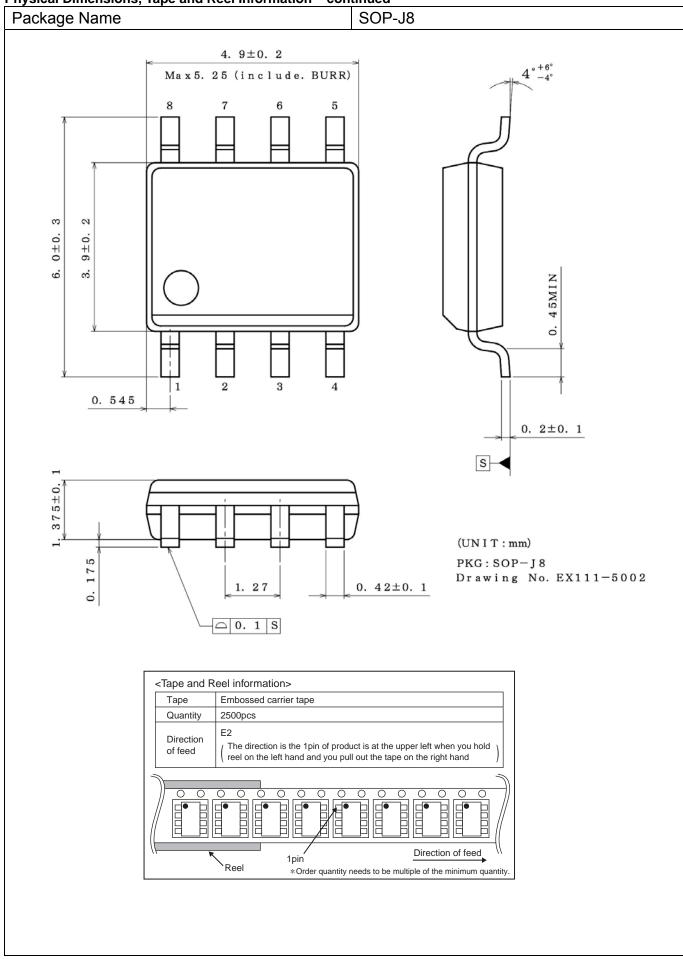


Figure 68. Example of monolithic IC structure

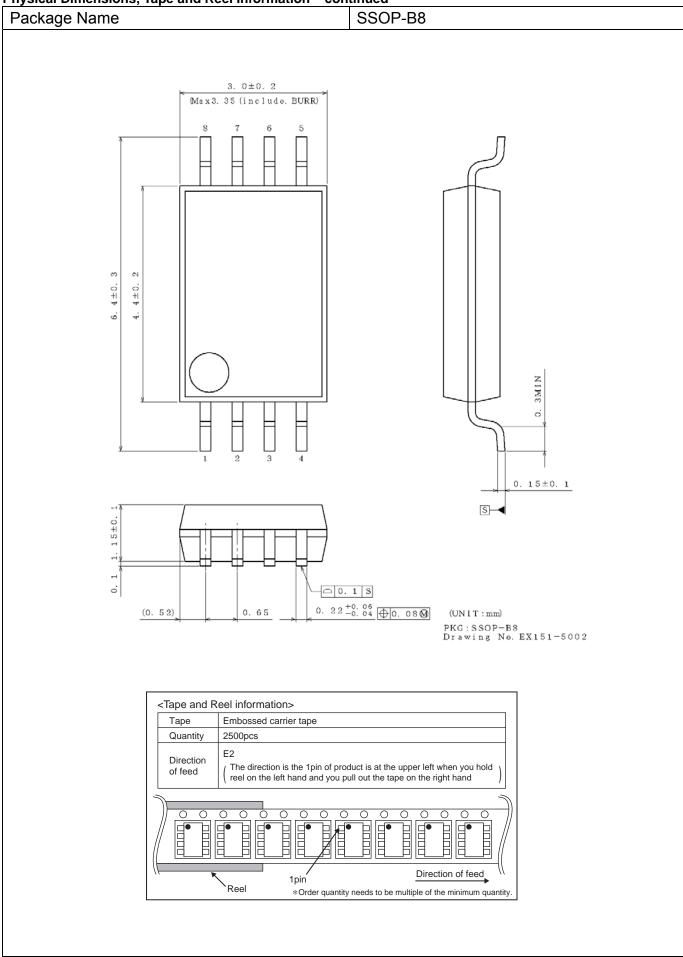
### Physical Dimensions, Tape and Reel Information



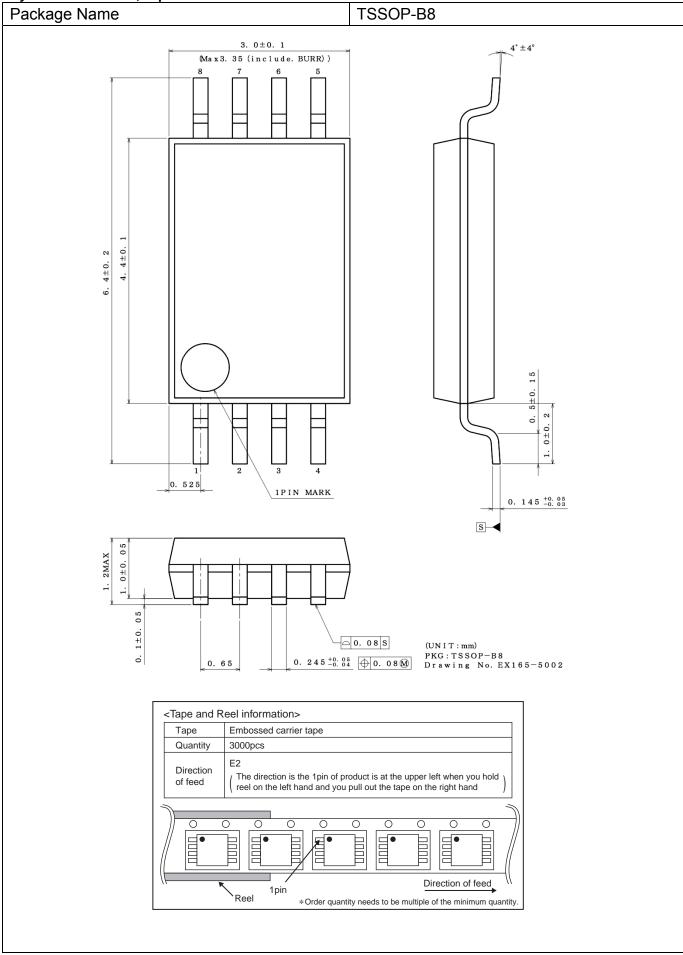
### Physical Dimensions, Tape and Reel Information - continued



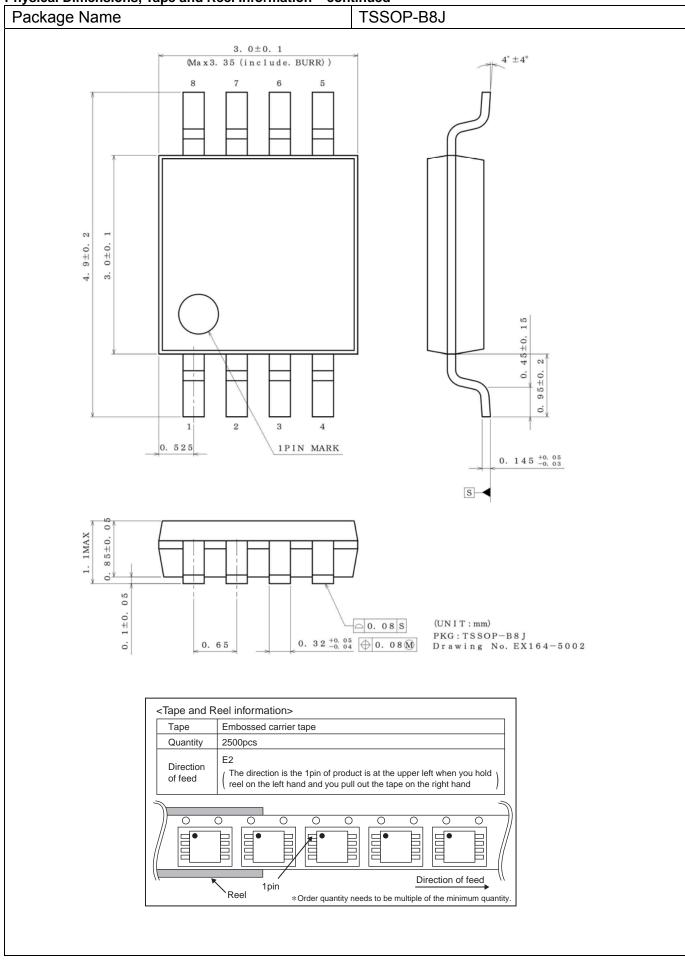




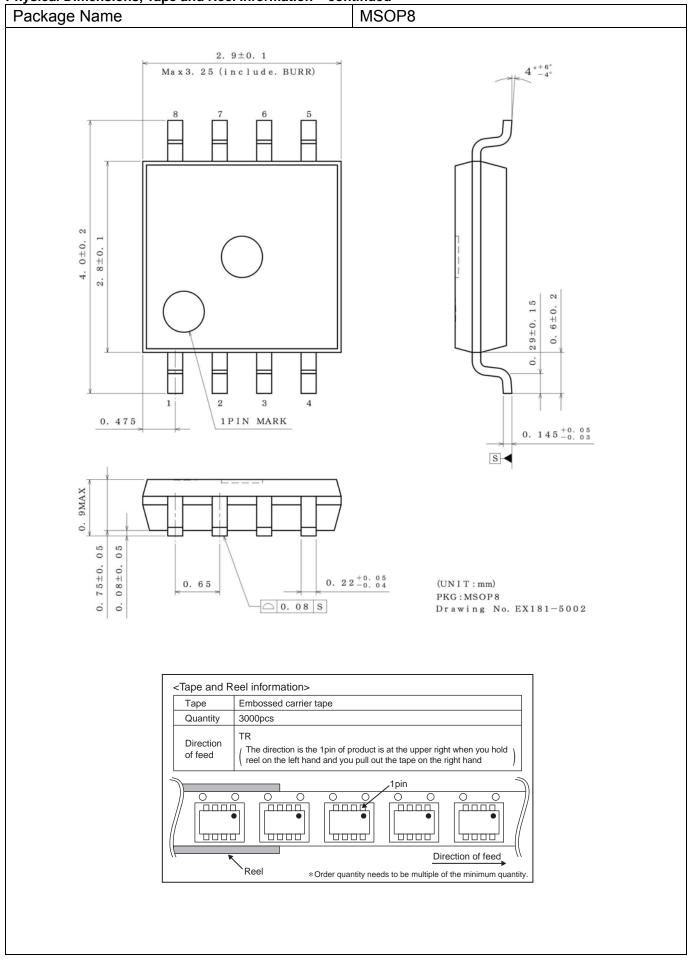




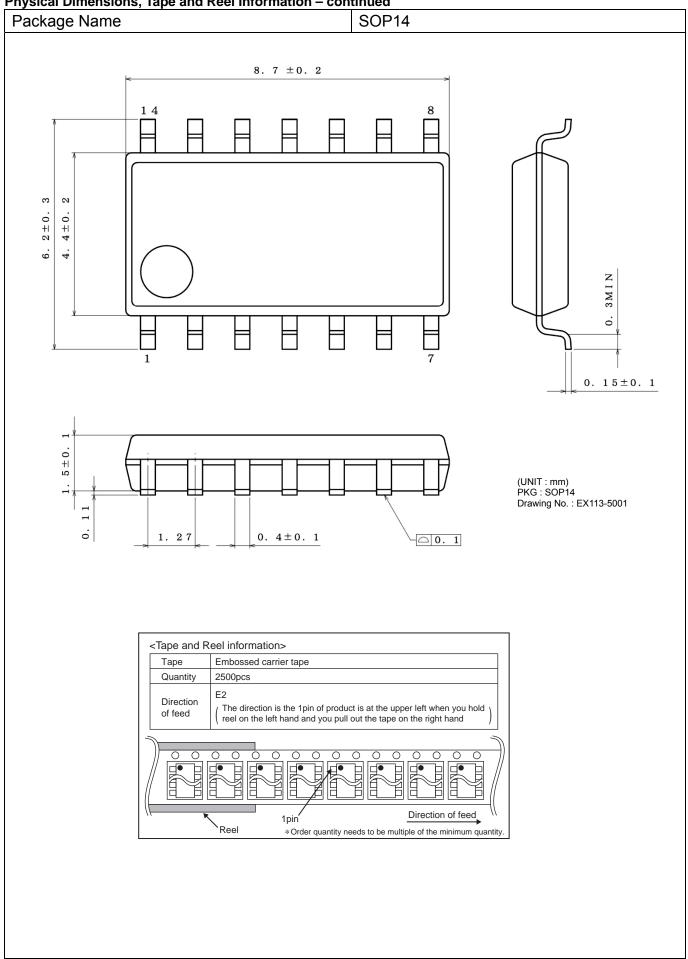




### Physical Dimensions, Tape and Reel Information - continued

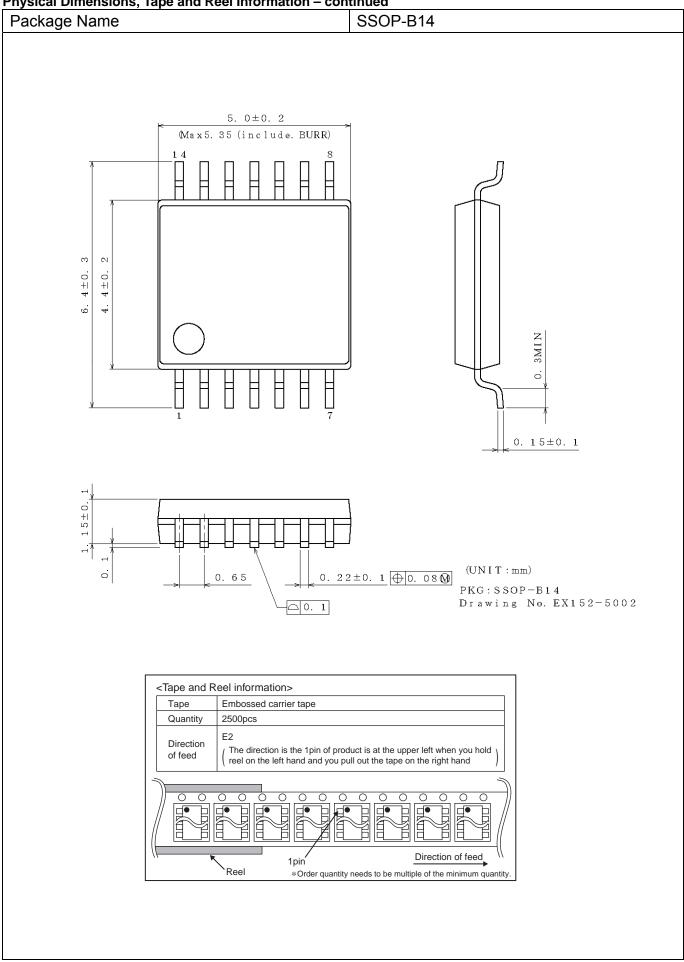






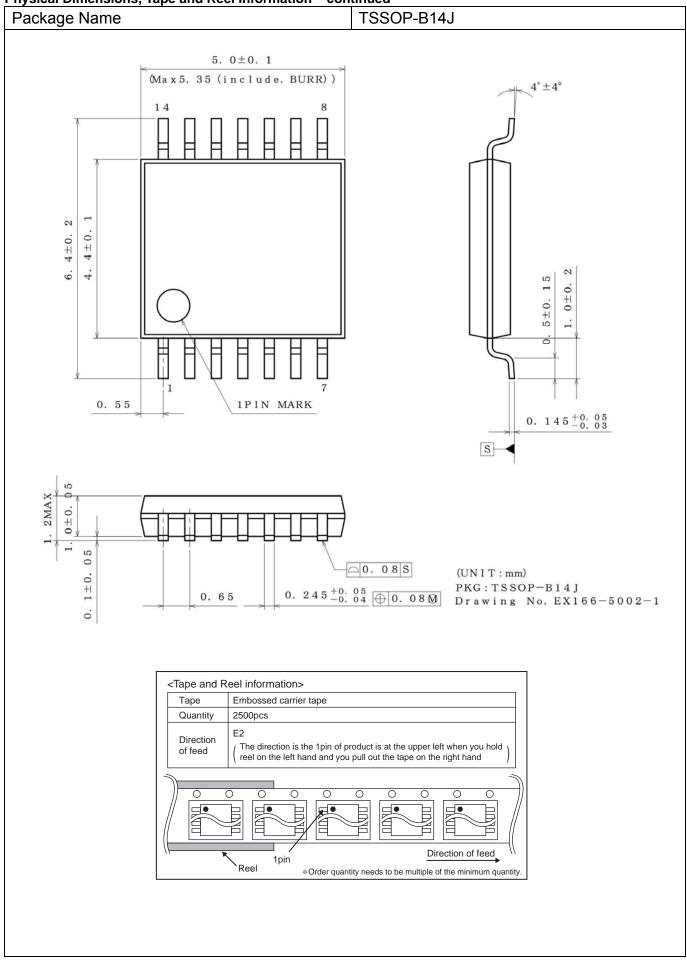
# Physical Dimensions, Tape and Reel Information - continued Package Name SOP-J14 8. $65\pm0.1$ (Max9. 0 (include. BURR)) $4^{\circ}^{+6^{\circ}}_{-4^{\circ}}$ 14 8 2 $0\pm 0$ . $9\pm0.$ 2 $65\pm0.15$ $1.05\pm0.$ .9 з. 0 1 1PIN MARK 0.515 0. $22^{+0.05}_{-0.03}$ S 375±0.075 1. 65MAX (UNIT:mm) 075 PKG:SOP-J14 Drawing No. EX126-5002-1 $175\pm0.$ $0. \ 4\ 2\ {}^{+0. \ 0\ 5}_{-0. \ 0\ 4} \ \bigoplus \ 0. \ 0\ 8\ M$ 1.27 0. 08S 0. <Tape and Reel information> Таре Embossed carrier tape Quantity 2500pcs E2 Direction The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand of feed С 0 Direction of feed 1pin Reel \*Order quantity needs to be multiple of the minimum quantity





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#### Physical Dimensions, Tape and Reel Information - continued



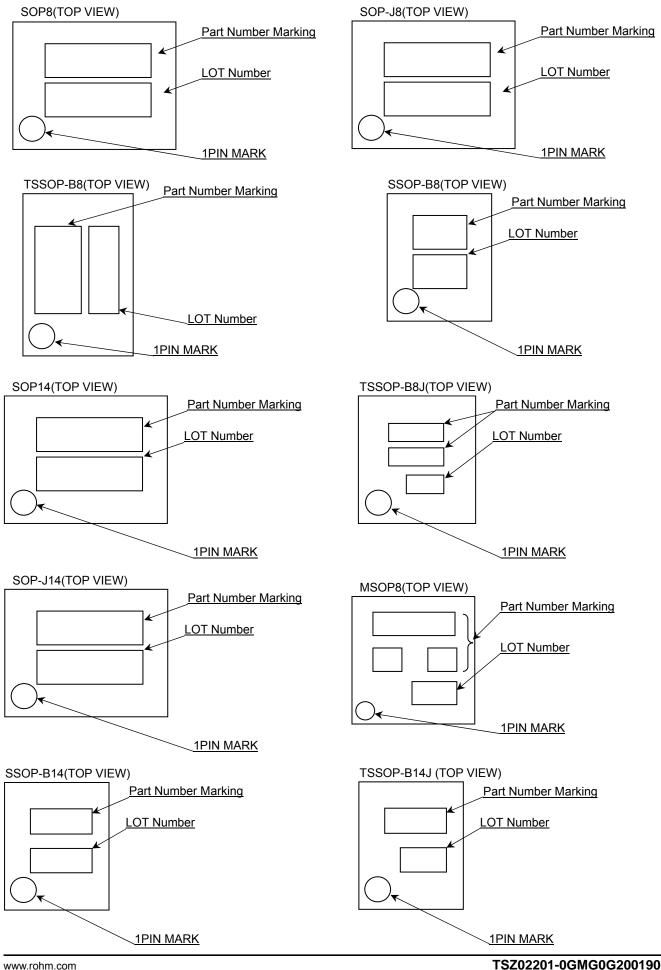
## **Ordering Information**

L M	х	х	Х	х	х	х	-	х	х	
Part Number LM358F LM358FJ LM358FV LM358FVJ LM358FVJ LM358FVJ LM324FVJ LM324FJ LM324FV LM324FVJ LM2904FV LM2904FV LM2904FVJ LM2904FVM LM2904FVM LM2902F LM2902FV LM2902FV				Packa     F     FJ     FV     FVT     FVJ     FVM	age : S( : S( : S( : S( : S( : S( : S( : S(	DP8 DP14 DP-J8 DP-J14 SOP-B1 SSOP-E SSOP-E SSOP-E SSOP3	3 14 38 38J	Pack E2: E	aging a Embosse (SOP8/S TSSOP-E	nd forming specification ed tape and reel SOP-J8/SSOP-B8/ B8/ SOP14/SOP-J14/ B14/TSSOP-B14J) ed tape and reel 3)

#### Line-up

Operating Temperature Range	Channel	Pac	kage	Orderable Part Number	
	2.ch	SOP8	Reel of 2500	LM358F-E2	
		SOP-J8	Reel of 2500	LM358FJ-E2	
		SSOP-B8	Reel of 2500	LM358FV-E2	
	2ch	TSSOP-B8	Reel of 3000	LM358FVT-E2	
-40°C to +85°C		TSSOP-B8J	Reel of 2500	LM358FVJ-E2	
-40 C 10 +85 C		MSOP8	Reel of 3000	LM358FVM-TR	
		SOP14	Reel of 2500	LM324F-E2	
	4ch	SOP-J14	Reel of 2500	LM324FJ-E2	
	401	SSOP-B14	Reel of 2500	LM324FV-E2	
		TSSOP-B14J	Reel of 2500	LM324FVJ-E2	
		SOP8	Reel of 2500	LM2904F-E2	
		SOP-J8	Reel of 2500	LM2904FJ-E2	
	Och	SSOP-B8	Reel of 2500	LM2904FV-E2	
	2ch	TSSOP-B8	Reel of 3000	LM2904FVT-E2	
-40°C to +125°C		TSSOP-B8J	Reel of 2500	LM2904FVJ-E2	
-40 C t0 + 125 C		MSOP8	Reel of 3000	LM2904FVM-TR	
	1ch	SOP14	Reel of 2500	LM2902F-E2	
		SOP-J14	Reel of 2500	LM2902FJ-E2	
	4ch	SSOP-B14	Reel of 2500	LM2902FV-E2	
		TSSOP-B14J	Reel of 2500	LM2902FVJ-E2	

# Marking Diagram



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### Marking Diagram – continued

Product	Name	Package Type	Marking	
	F	SOP8		
	FJ	SOP-J8		
LM358	FV	SSOP-B8	250	
	FVT	TSSOP-B8	358L	
	FVJ	TSSOP-B8J		
	FVM	MSOP8		
	F	SOP14	LM324F	
1.11224	FJ	SOP-J14	LM324FJ	
LM324	FV	SSOP-B14	324L	
	FVJ	TSSOP-B14J	324L	
	F	SOP8	- 2904L	
	FJ	SOP-J8		
1 10000 4	FV	SSOP-B8	04L	
LM2904	FVT	TSSOP-B8		
	FVJ	TSSOP-B8J	2904L	
	FVM	MSOP8		
	F	SOP14	LM2902F	
1 M2002	FJ	SOP-J14	LM2902FJ	
LM2902	FV	SSOP-B14	- 2902L	
	FVJ	TSSOP-B14J		

# **Revision History**

Date	Revision	Changes
10.Jul.2015	001	New Release
09.Oct.2015	002	LM358FJ, LM358FV, LM358FVT, and LM324F are added
10.Feb.2016	003	LM2904xxx (F, FJ, FV, FVT, FVM, FVJ), and LM358xxx (FVM, FVJ) are added
06.Jun.2016	004	LM324xxx (FJ, FV, FVJ), and LM2902xxx (F, FJ, FV, FVJ) are added
01.Aug.2016	005	Correction of erroneous description (P.4 Icc Full Range 1.5→2.5mA) Delete Land Pattern Data(P.44)

# Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JÁPAN	USA	EU	CHINA	
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII	
CLASSⅣ	CLASSII	CLASSⅢ	CLASSI	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
  - [a] Installation of protection circuits or other protective devices to improve system safety
  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

#### Precaution for Foreign Exchange and Foreign Trade act

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

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#### **General Precaution**

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# **ROHM Semiconductor:**

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